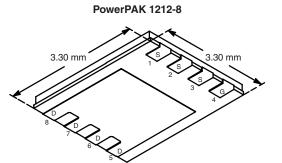


Vishay Siliconix

N-Channel 30-V (D-S) Fast Switching MOSFET

| PRODUCT SUMMARY | | | | |
|---------------------|----------------------------------|--------------------|--|--|
| V _{DS} (V) | R_{DS(on)} (Ω) | I _D (A) | | |
| 30 | 0.0195 at V _{GS} = 10 V | 10 | | |
| | 0.030 at V _{GS} = 4.5 V | 8 | | |



Bottom View

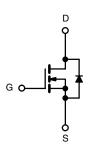
Ordering Information: Si7326DN-T1-E3 (Lead (Pb)-free) Si7326DN-T1-GE3 (Lead (Pb)-free and Halogen-free)

FEATURES

- Halogen-free According to IEC 61249-2-21
 Available
- TrenchFET[®] Power MOSFET
- New Low Thermal Resistance PowerPAK[®] Package with Low 1.07 mm Profile
- 100 % R_g Tested

APPLICATIONS

DC/DC Conversion



N-Channel MOSFET

| ABSOLUTE MAXIMUM RATINGS $T_A = 25 \text{ °C}$, unle Parameter | | Symbol | 10 s | Steady State | Unit |
|--|------------------------|-----------------------------------|-------------|--------------|------|
| Drain-Source Voltage | | V _{DS} | 30 | | V |
| Gate-Source Voltage | | V _{GS} | ± 25 | | |
| | T _A = 25 °C | - I _D | 10 | 6.5 | |
| Continuous Drain Current (T _J = 150 °C) ^a | T _A = 70 °C | | 7.5 | 5.0 | |
| Pulsed Drain Current | | I _{DM} | 40 | | А |
| Continuous Source Current (Diode Conduction) ^a | | ۱ _S | 2.9 | 1.2 | |
| Single Pulse Avalanche Current | L = 0.1 mH | I _{AS} | 15 11 | | |
| Avalanche Energy | L = 0.1 IIIH | E _{AS} | | | mJ |
| | T _A = 25 °C | – P _D | 3.5 | 1.5 | W |
| Maximum Power Dissipation ^a | T _A = 70 °C | | 1.9 | 0.8 | |
| Operating Junction and Storage Temperature Range | | T _J , T _{stg} | - 55 to 150 | | °C |
| Soldering Recommendations (Peak Temperature) ^{b, c} | | _ | 260 | | |

| THERMAL RESISTANCE RATINGS | | | | | |
|--|--------------|-------------------|---------|---------|------|
| Parameter | | Symbol | Typical | Maximum | Unit |
| Maximum lunation to Ambienta | $t \le 10 s$ | R _{thJA} | 28 | 35 | |
| Maximum Junction-to-Ambient ^a | Steady State | | 65 | 81 | °C/W |
| Maximum Junction-to-Case (Drain) | Steady State | | 4.5 | 6.0 | |

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

b. See Solder Profile (<u>www.vishay.com/ppg?73257</u>). The PowerPAK 1212-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.

c. Rework Conditions: manual soldering with a soldering iron is not recommended for leadless components.





| Parameter | Symbol | Test Conditions | Min. | Тур. | Max. | Unit | |
|---|--|---|------|-------|--------|------|--|
| Static | | | | • | | | |
| Gate Threshold Voltage | $V_{GS(th)}$ $V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$ | | 0.8 | | 1.8 | V | |
| Gate-Body Leakage | I _{GSS} | $V_{DS} = 0 V, V_{GS} = \pm 20 V$ | | | ± 100 | nA | |
| Zero Gate Voltage Drain Current | I _{DSS} - | $V_{DS} = 30 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$ | | | 1 | | |
| | | V_{DS} = 30 V, V_{GS} = 0 V, T_{J} = 55 °C | | | 5 | μA | |
| On-State Drain Current ^a | I _{D(on)} | $V_{DS} \ge 5 \text{ V}, \text{ V}_{GS} = 10 \text{ V}$ 30 | | | | Α | |
| Drain-Source On-State Resistance ^a | R _{DS(on)} | V _{GS} = 10 V, I _D = 10 A | | 0.015 | 0.0195 | | |
| | | $V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 8 \text{ A}$ | | 0.022 | 0.030 | Ω | |
| Forward Transconductance ^a | 9 _{fs} | V _{DS} = 15 V, I _D = 10 A | | 16 | | S | |
| Diode Forward Voltage ^a | V _{SD} | $I_{S} = 2.9 \text{ A}, V_{GS} = 0 \text{ V}$ | | 0.75 | 1.2 | V | |
| Dynamic ^b | • | | • | • | | | |
| Total Gate Charge | Qg | | | 8.7 | 13 | nC | |
| Gate-Source Charge | Q _{gs} | V_{DS} = 15 V, V_{GS} = 5 V, I_{D} = 10 A | | 1.5 | | | |
| Gate-Drain Charge | Q _{gd} | | | 3.5 | | 1 | |
| Gate Resistance | Rg | | 0.5 | 1.4 | 2.2 | Ω | |
| Turn-On Delay Time | t _{d(on)} | | | 8 | 15 | | |
| Rise Time | t _r | V_{DD} = 15 V, R_L = 15 Ω | | 12 | 20 | ns | |
| Turn-Off Delay Time | t _{d(off)} | $\text{I}_\text{D}\cong \text{1}$ A, V_GEN = 10 V, R_g = 6 Ω | | 32 | 50 | | |
| Fall Time | t _f | | | 14 | 25 | | |
| Source-Drain Reverse Recovery Time | t _{rr} | I _F = 2.9 A, dI/dt = 100 A/μs | | 30 | 60 | | |

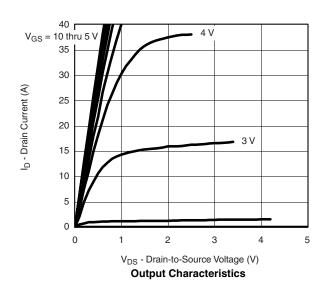
Notes:

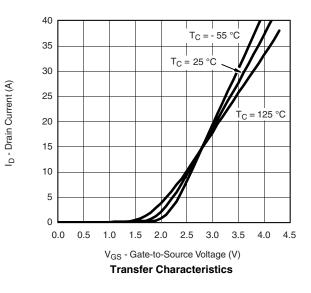
a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

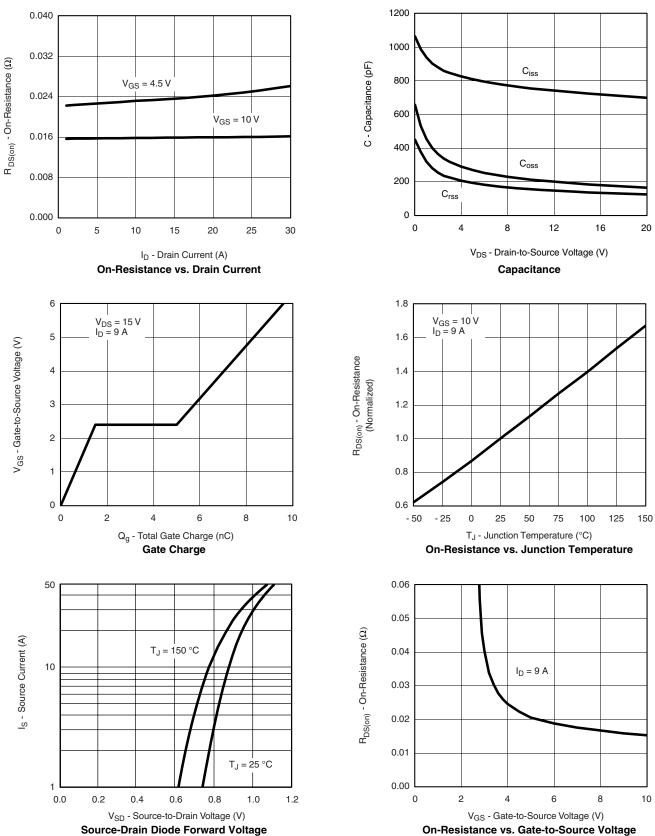




Si7326DN Vishay Siliconix



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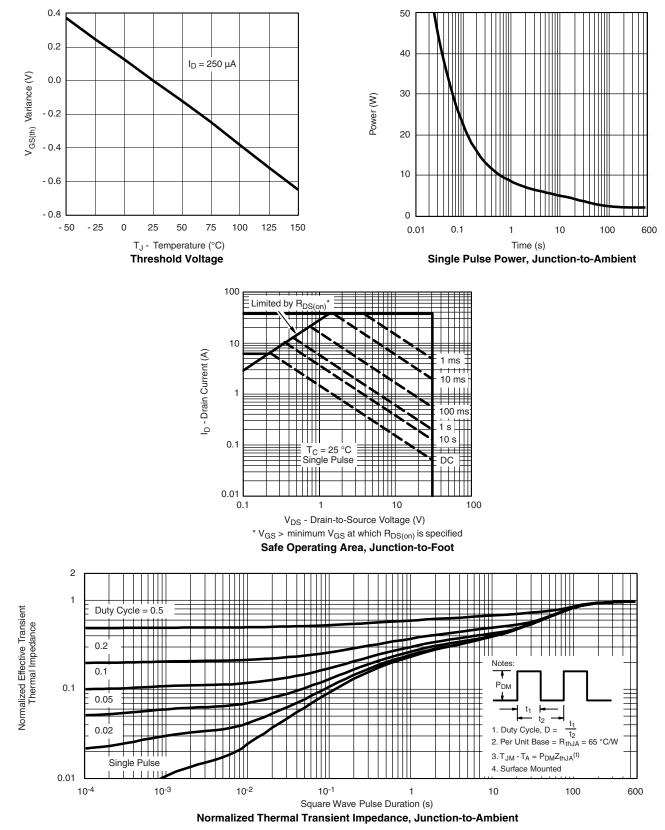


Document Number: 74444 S-83051-Rev. C, 29-Dec-08

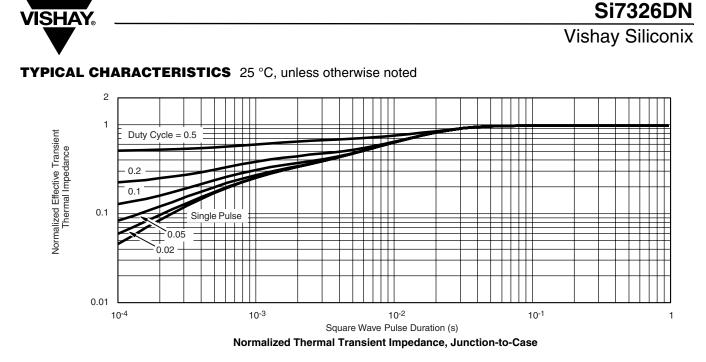
Si7326DN

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package/tape drawings, part marking, and reliability data, see <u>www.vishay.com/ppg?74444</u>.



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